

# **TMR2901**

Ultra High Sensitivity TMR linear sensor

### **General Description**

The TMR2901 linear sensor utilizes a unique push-pull Wheatstone bridge composed of four TMR sensor elements. The TMR2901 is available in a 3 mm X 3 mm X 0.75 mm DFN8 package and 6mm X 5mm X 1.5mm SOP8 package.

### **Features and Benefits**

- Tunneling Magneto resistance (TMR) Technology
- High Sensitivity (25mV/V/Oe)
- Very Low Noise Spectral Density (2nT/ √Hz @1Hz)
- Low Power Consumption
- Excellent Thermal Stability
- Very Low Hysteresis
- Compatible with wide Range of Supply Voltages
- NO need for set/reset calibration

# The Mary

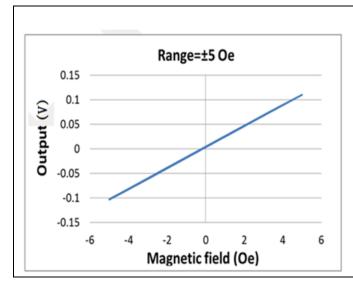
TMR2901

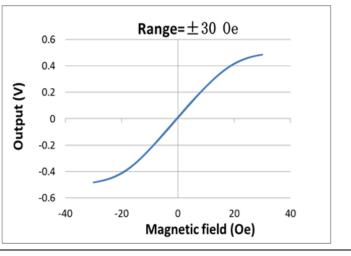
### **Applications**

- Weak Magnetic Field Sensing
- Current Sensors
- Position and Displacement Sensing

### **Transfer Curve**

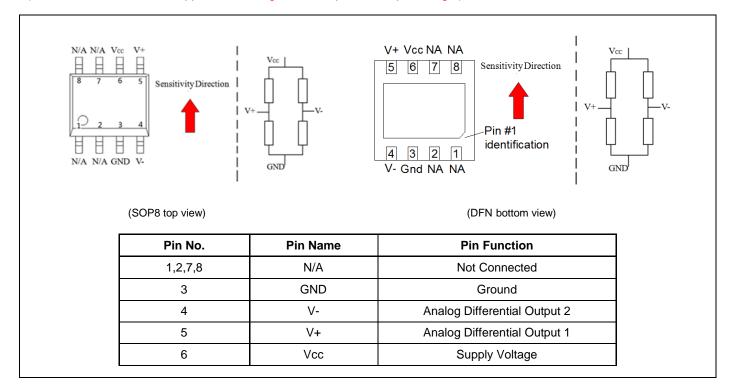
The following figure shows the response of the TMR2901 to an applied magnetic field in the range of ±5 Oe and ±30 Oe when the TMR2901 is biased at 1V.





### **Pin Configuration**

(Arrow indicates direction of applied field that generates a positive output voltage.)



### **Absolute Maximum Ratings**

Parameter	Symbol	Limit	Unit
Supply Voltage	V <sub>CC</sub>	7	V
Reverse Supply Voltage	V <sub>RCC</sub>	7	V
Max Exposed Field	H <sub>E</sub>	4000	Oe <sup>(1)</sup>
ESD Voltage	$V_{ESD}$	4000	V
Operating Temperature	T <sub>A</sub>	-40~125	°C
Storage Temperature	T <sub>stg</sub>	-50 ~150	°C

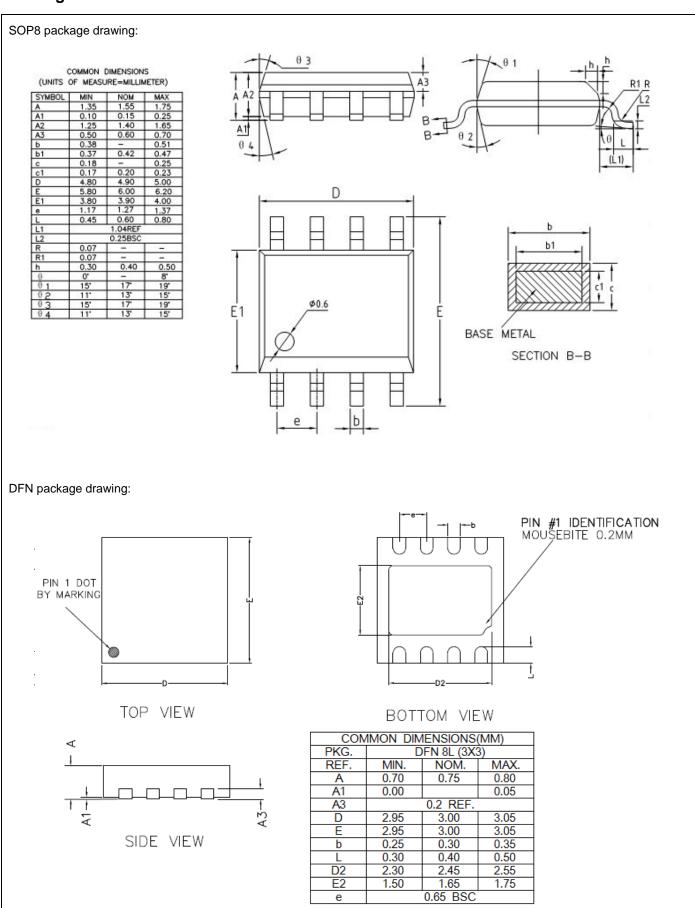
## Specification (V<sub>CC</sub>=1.0V, T<sub>A</sub>=25°C,Differential Output)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	Vcc	Operating		1	7	V
Supply Current	Icc	Output Open		0.1 <sup>(2)</sup>		mA
Resistance	R		7	45, 9	10	KOhm
Sensitivity	SEN	Fit @±1 Oe	20	25	27	mV/V/Oe
Saturation Field	H <sub>sat</sub>			±20		Oe
Non-Linearity	NONL	Fit @±1 Oe		0.3		%FS
Offset Voltage	V <sub>offset</sub>		-10		10	mV/V
Hysteresis	Hys	Fit @±1 Oe			0.2	Oe
Temperature Coefficient of	TCR	H = 0 Oe		-500		PPM/°C
Resistance						
Temperature Coefficient of	TCS			-1100		PPM/°C
Sensitivity						
Self Noise	Ni	@1Hz		2		nT/ √ Hz

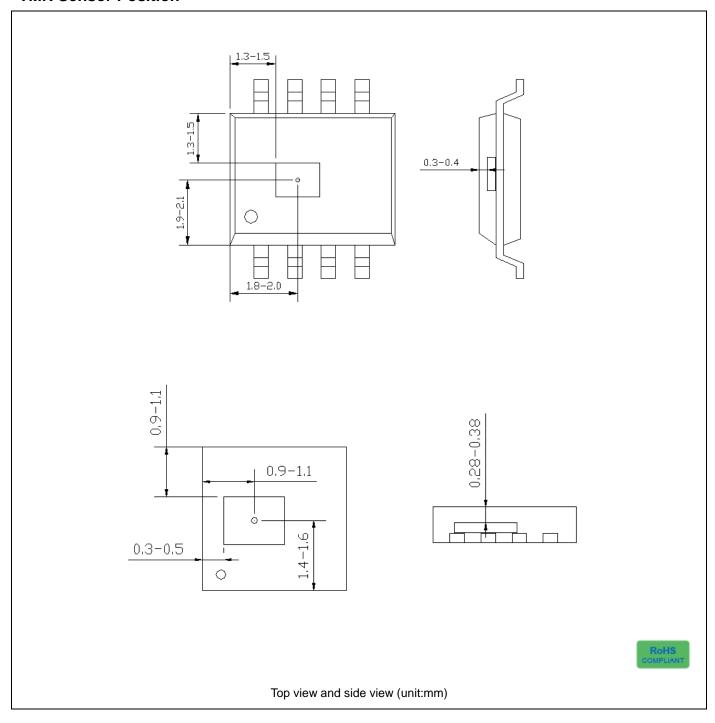
Notes:

- (1) 1 Oe (Oersted) = 1 Gauss in air = 0.1 millitesla = 79.8 A/m.
- (2) Custom resistance may be available upon request.

### **Package Information**



## **TMR Sensor Position**









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